Product data sheet

1 Product profile

1.1 General description

Two planar PIN diodes in common anode configuration in an SOT323 small SMD plastic package.

1.2 Features and benefits

- Two elements in common anode configuration in a small SMD plastic package
- · Low diode capacitance
- · Low diode forward resistance
- AEC-Q101 qualified

1.3 Applications

· General RF applications

2 Pinning information

Table 1. Discrete pinning

| Pin | Description | Simplified outline | Graphic symbol |
|-----|----------------|--------------------|-------------------|
| 1 | cathode 1 | | |
| 2 | cathode 2 | 3 | _ |
| 3 | common cathode | 1 2 sot323_so | 2 1 aaa-029922 |

3 Ordering information

Table 2. Ordering information

| Table 21 Ordering morniation | | | | | | |
|------------------------------|---------|--|---------|--|--|--|
| Type number | Package | ackage | | | | |
| | Name | Description | Version | | | |
| BAP51-06W | - | plastic surface-mounted package; 3 leads | SOT323 | | | |



BAP51-06W

Silicon PIN diode

4 Marking

Table 3. Marking

| Type number | Marking code | Description |
|-------------|--------------|--------------------------|
| BAP51-06W | W7% | % = p: made in Hong Kong |
| | | % = t: made in Malaysia |

5 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|-------------------------|-----|------|------|
| V_R | reverse voltage | | - | 50 | V |
| I _F | forward current | | - | 50 | mA |
| P _{tot} | total power dissipation | T _{sp} ≤ 90 °C | - | 240 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | -65 | +150 | °C |

6 Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|--------|--|------------|-----|------|
| (J OP) | thermal resistance from junction to solder point | | 250 | K/W |

7 Characteristics

Table 6. Characteristics

 T_i = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | |
|------------------|--------------------------|---|-------|------|------|------|--|
| V_{F} | forward voltage | I _F = 50 mA | - | 0.95 | 1.1 | V | |
| I _R | reverse current | V _R = 50 V | - | - | 100 | nA | |
| C _d | diode capacitance | f = 1 MHz (see Figure 1) | | | | | |
| | | V _R = 0 V | - | 0.4 | - | pF | |
| | | V _R = 1 V | - | 0.3 | 0.55 | pF | |
| | | V _R = 5 V | - | 0.2 | 0.35 | pF | |
| r _D | diode forward resistance | f = 100 MHz (see Figure 2) | | | | | |
| | | I _F = 0.5 mA | [1] _ | 5.3 | 9 | Ω | |
| | | I _F = 1 mA | [1] _ | 3.5 | 6.5 | Ω | |
| | | I _F = 10 mA | [1] _ | 1.5 | 2.5 | Ω | |
| ISL | isolation | V _R = 0 V (see <u>Figure 4</u>) | | | | - | |
| | | f = 900 MHz | - | 17 | - | dB | |
| | | f = 1800 MHz | - | 13 | - | dB | |
| | | f = 2450 MHz | - | 12 | - | dB | |
| L _{ins} | insertion loss | I _F = 0.5 mA (see <u>Figure 3</u>) | | | | | |
| | | f = 900 MHz | - | 0.44 | - | dB | |
| | | f = 1800 MHz | - | 0.50 | - | dB | |
| | | f = 2450 MHz | - | 0.54 | - | dB | |
| | | I _F = 1 mA | | | | | |
| | | f = 900 MHz | - | 0.33 | - | dB | |
| | | f = 1800 MHz | - | 0.39 | - | dB | |
| | | f = 2450 MHz | - | 0.43 | - | dB | |
| | | I _F = 10 mA | | | | | |
| | | f = 900 MHz | - | 0.19 | - | dB | |
| | | f = 1800 MHz | - | 0.24 | - | dB | |
| | | f = 2450 MHz | - | 0.28 | - | dB | |
| τι | charge carrier life time | when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω ; measured at I_R = 3 mA | - | 0.55 | - | μs | |
| L _S | series inductance | I _F = 100 mA; f = 100 MHz | - | 1.6 | - | nH | |

^[1] Guaranteed on AQL basis; inspection level S4, AQL 1.0

8 Graphical data

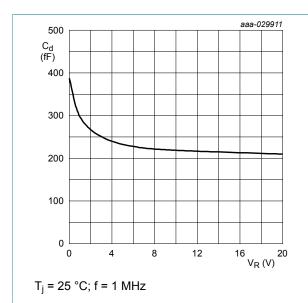
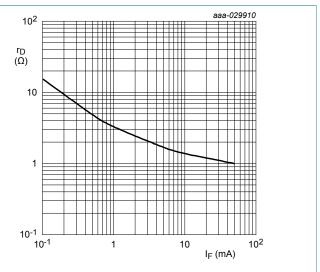
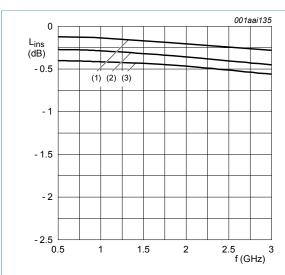


Figure 1. Diode capacitance as a function of reverse voltage (typical values)



 T_j = 25 °C; f = 100 MHz.

Figure 2. Diode forward resistance as a function of forward current (typical values)



Diode inserted in series with a 50 Ω strip line circuit and biased via the analyzer T-network.

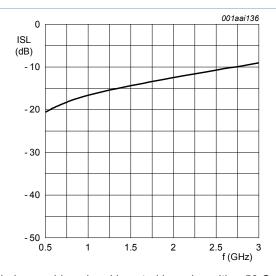
 T_{amb} = 25 °C; f = 1 MHz

(1) $I_F = 10 \text{ mA}$

(2) $I_F = 1 \text{ mA}$

(3) $I_F = 0.5 \text{ mA}$

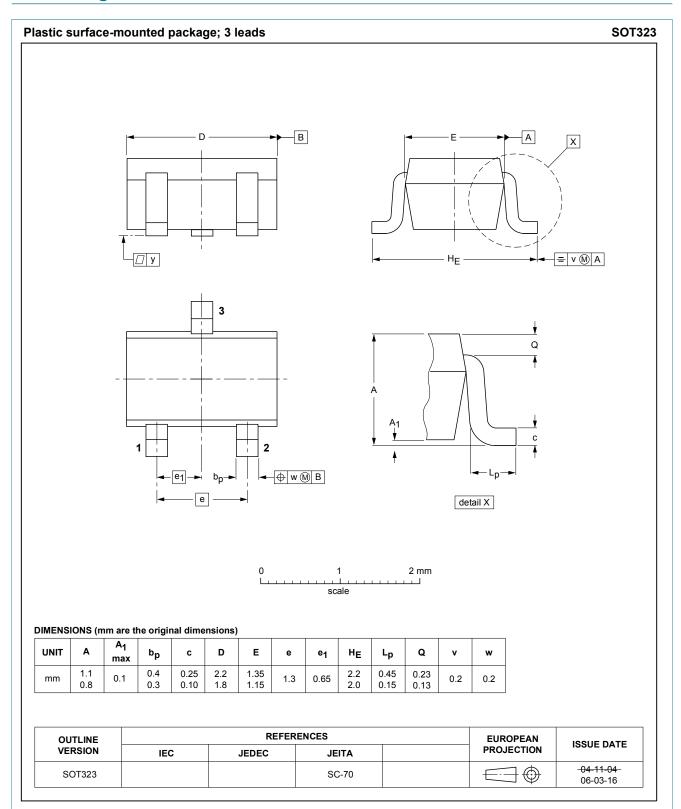
Figure 3. Insertion loss of the diode as a function of frequency (typical values)



Diode zero-biased and inserted in series with a 50 Ω strip line circuit T_{amb} = 25 $^{\circ}C$

Figure 4. Isolation of the diode as a function of frequency (typical values)

9 Package outline



10 Abbreviations

Table 7. Abbreviations

| Acronym | Description |
|---------|----------------------------|
| AQL | acceptable quality level |
| PIN | P-type, intrinsic, N-type |
| RF | radio frequency |
| S4 | special inspection level 4 |
| SMD | surface-mounted device |

11 Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-----------------|---|--------------------|---------------|---------------|
| BAP51-06W v.2.1 | 20190208 | Product data sheet | - | BAP51-06W v.2 |
| Modifications: | odifications: • aligned the title of the data sheet with the description on the Internet | | | |
| BAP51-06W v.2 | 20181126 | Product data sheet | - | BAP51-06W v.1 |
| Modifications: | Section 1.2 "Features and benefits" has been updated. The "Legal information" pages have been updated. | | | |
| BAP51-06W v.1 | 20080526 | Product data sheet | - | - |

12 Legal information

12.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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- [2] The term 'short data sheet' is explained in section "Definitions".
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